

SANYO Semiconductors DATA SHEET



BI-CMOS LSI Eight-Channel Switching Regulator Controller

Overview

The LV5604T is a eight-channel switching regulator controller.

Features

- Low-voltage (3V) operation
- Reference voltage precision : ±1%
- Independent standby functions for each of the eight channels
- Is capable of driving MOS transistors
- Synchronous rectification : channel 1 and channel 2
- Supports inverting step-up operation.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		16	V
Allowable power dissipation	Pd max		1	W
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		3 to 15	V
Supply voltage	VBIAS		3 to 15	V
Timing resistor	RT		7 to 30	kΩ
Timing capacitor	СТ		100 to 1000	pF
Triangle wave frequency	fosc		0.1 to 1.3	MHz

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LV5604T

Electrical Characteristics at Ta = 25° C, V_{CC} = VBIAS = 3.6V, SCP = 0V

Parameter		Sumbol	Conditions	Ratings			Lipit
		Symbol		min	typ	max	Unit
Error amplifier 1	Error amplifier 1						
IN ⁺ pin internal bias voltag	e	VB	Value added to the error amplifier	0.509	0.515	0.521	V
			offset at the error amplifier + side voltage				
Output low voltage	ch1 to ch8	V _{Low} FB	IN ⁻ = 2.0V, IFB = 20μA			0.2	V
Output high voltage	ch1 to ch8	V _{Hi} FB	IN ⁻ = 0V IFB1 = -20µA	2.0			V
Error amplifier 2							
IN5 ⁻ RE pin offset voltage		VOF		-6		6	mV
Output low voltage		V _{Low} FB5RE	$IN5^{-}RE = 2.0V, IFB = 20\mu A$			0.2	V
Output high voltage		V _{Hi} FB5RE	FB5RE ; H, IFB = 500µA	1.95			V
Protection circuit							
Threshold voltage		V _{SCP}		1.1	1.25	1.4	V
SCP pin current		ISCP			4		μA
Short circuit detection sign	al pin	VSCPOUT	Open collector			0.2	V
			ISCPOUT = 100μA				
Software start block (ch1	to ch8)	1	Γ				
Soft start current	ch1 to ch8	ISF	CSOFT1 to 8 = 0V	3.2	4	4.8	μA
Soft start resistance	ch1 to ch8	R _{SF}		160	200	240	kΩ
Fixed duty		1	Γ				
Maximum on duty 1	ch1 to ch4	Duty MAX 1 to 4	Out monitor, IN⁻ = 0V	100			%
Maximum on duty 2	ch5	Duty MAX 5	Out monitor, IN⁻ = 0V	80	85	90	%
Maximum on duty 3	ch6 to ch8	Duty MAX 6 to 8	Out monitor, IN⁻ = 0V	80	85	90	%
Output block 1 to 6		1	Γ				
OUT pin high side on resistance		R _{OUT} SOUR	I _O = 10mA		25		Ω
OUT pin high side on resistance		R _{OUT} SINK	I _O = 10mA		10		Ω
Triangle wave oscillator block							
Current setting pin voltage		VT RT	RT = 10kΩ		0.57		V
Output current		I _{OH} CT			220		μA
Output current ratio		∆I _O CT	CT pin, ISOURCE/ISINK		2.5		
Oscillation frequency		fosc1	RT = 10kΩ, CT = 270pF	390	490	570	kHz
Reference voltage block		T	1	1			
Reference voltage		VREF			1.230		V
Line regulation		V_{LN} REF	$V_{CC} = 3V$ to 15V			10	mV
Control circuit		1	1	I			
On state voltage		V _{ON} CTL		2.0			V
OFF state voltage		V _{OFF} CTL				0.6	V
Pin input current		I _{IN} CTL	VCTL = 2V			60	μΑ
Standby circuit							
On voltage		V _{ON} STBY		2.0			V
Off voltage		V _{OFF} STBY				0.6	V
Pin input current		I _{IN} STBY	VSTBY = 2V			60	μA
All circuits							
V_{CC} current consumption		ICC	IN1 ⁻ to IN8 ⁻ = 1V		6	7.5	mA
Standby mode current con	sumption	IOFF	VSTBY = VCTL = 0V			1	μA
			IOFF = ICC + IBIAS				

Package Dimensions

unit : mm (typ) 3289



Pin Assignment



No.A0966-3/12





Pin Functi	on		
Block	Pin No.	Pin Name	Functions
ch1	3	STBY1	Standby input. H/ch1 ; ON, L/ch1 ; OFF
(Step-down)	13	IN1 ⁻	Error amplifier Inverting input
	14	FB1	Error amplifier output
	61	OUT1	Output. External transistor P-channel gate connect
	62	OUT1N	Output. External transistor N-channel gate connection
	7	CSOFT1	Soft start setting capacitor connection. Connect to GND through a capacitor.
ch2	4	STBY2	Standby input. H/ch2 ; ON, L/ch2 ; OFF
(Step-down)	15	IN2 ⁻	Error amplifier Inverting input
	16	FB2	Error amplifier output
	60	OUT2	Output. External transistor P-channel gate connection
	59	OUT2N	Output. External transistor N-channel gate connection
	8	CSOFT2	Soft start setting capacitor connection. Connect to GND through a capacitor.
ch3	5	STBY3	Standby input. H/ch3 ; ON, L/ch3 ; OFF
(Step-down)	17	IN3 ⁻	Error amplifier Inverting input
	18	FB3	Error amplifier output
	9	CSOFT3	Soft start setting capacitor connection. Connect to GND through a capacitor.
	57	OUT3	Output. External transistor P-channel gate connection
ch4	6	STBY4	Standby input. H/ch4 ; ON, L/ch4 ; OFF
(Step-down)	19	IN4 ⁻	Error amplifier Inverting input
	20	FB4	Error amplifier output
	10	CSOFT4	Soft start setting capacitor connection. Connect to GND through a capacitor.
	56	OUT4	Output. External transistor P-channel gate connection
ch5	42	STBY5	Standby input. H/ch5 ; ON, L/ch5 ; OFF
(Inversion)	28	IN5 ⁻ RE	Inversion step-up error amplifier, - (Inverting) input
	29	IN5 ⁺ RE	Inversion step-up error amplifier, + (noninverting) input
	27	FB5RE	Inversion step-up error amplifier output
	25	IN5 ⁻	Error amplifier Inverting input
	26	FB5	Error amplifier output
	38	CSOFT5	Soft start setting capacitor connection. Connect to GND through a capacitor.
	55	OUT5	Output. External transistor P-channel gate connection
ch6	43	STBY6	Standby input. H/ch6 ; ON, L/ch6 ; OFF
(Step-up)	30	IN6 ⁻	Error amplifier Inverting input
	31	FB6	Error amplifier output
	39	CSOFT6	Soft start setting capacitor connection. Connect to GND through a capacitor.
	53	OUT6	Output. External transistor N-channel gate connection
ch7	44	STBY7	Standby input. H/ch7 ; ON, L/ch7 ; OFF
(Step-up)	32	IN7 ⁻	Error amplifier Inverting input
	33	FB7	Error amplifier output
	40	CSOFT7	Soft start setting capacitor connection. Connect to GND through a capacitor.
	52	OUT7	Output. External transistor N-channel gate connection
ch8	45	STBY8	Standby input. H/ch8 ; ON, L/ch8 ; OFF
(Step-aown) (Step-up)	34	IN8 ⁻	Error amplifier Inverting input
(Crop up)	35	FB8	Error amplifier output
	41	CSOFT8	Soft start setting capacitor connection. Connect to GND through a capacitor.
F	51	OUT8	Output. External transistor (Step-up / N-channel, Step-down / P-channel) gate connection

Continued fror	n preceding	page.	
Block	Pin No.	Pin Name	Functions
MODE 64 SYNC1		SYNC1	Synchronous rectification/diode rectification switching, L : synchronous rectification H : diode rectification
	1	SYNC2	Synchronous rectification/diode rectification switching, L : synchronous rectification H : diode rectification
	36	SEL_CH8	Channel 8 step-up/step-down switching, L (GND) : step-up H (VBIAS2) : step-down
POWER	46	Vcc	Power supply input (signal system)
	2	VBIAS1	Power supply input (ch1 to ch4, pre-output stage)
	47	VBIAS2	Power supply input (ch5 to ch8, pre-output stage)
	24	GND_S	Ground (signal system)
	58	GND_P1 (VS1)	Ground (ch1 to ch4, pre-output stage)
	54	GND_P2 (VS2)	Ground (ch5 to ch8, pre-output stage)
	23	VREF	Reference voltage output
CONTROL	37	CTL	Power supply control
	11	SCP	Connection pin for the delay time setting capacitor of short circuit detection circuit
	12	SCP_OUT	Short circuit detection circuit output
OSC	21	СТ	Triangle wave oscillation frequency setting capacitor connection
	22	RT	Triangle wave oscillation frequency setting resistor connection
	48	CLKIN	External clock input
	49	CLKOUT	Clock output
OTHER	63	(NC)	No connection
	50	(NC)	No connection

Equivalent Circuits			
Pin No.	Pin Name	Description	Equivalent Circuit
37 3 4 5 6 42 43 44 45	CTL STBY1 STBY2 STBY3 STBY4 STBY5 STBY6 STBY7 STBY8	CTL : Controls operation of all channels. STBY* : Independently controls operation of the corresponding channel. Operation is high active. High : Circuit operation ON Low : Circuit operation OFF	CTL/STBY*
13 15 17 19 25 30 32 34	IN1 ⁻ IN2 ⁻ IN3 ⁻ IN4 ⁻ IN5 ⁻ IN6 ⁻ IN7 ⁻ IN8 ⁻	Error amplifier inverting input. The regulator output is divided by a resistor and connected to IN*-	VREG (Internal constant voltage) IN*- 500Ω 500Ω 500Ω 500Ω 500Ω 500Ω GND_S
14 16 20 26 31 33 35	FB1 FB2 FB3 FB4 FB5 FB6 FB7 FB8	Error amplifier output. These pins, in combination with IN*-, configure the error amplifier filters	FB*
29 28	IN5 ⁺ RE IN5 ⁻ RE	Inversion step-up (Channel 5) error amplifier input. These pins, in combination with FB5R, configure the operational amplifier (independent)	$IN5^{-}RE \bigcirc W \\ 500\Omega & \bigcirc IN5^{+}RE \\ 55k\Omega & 55k\Omega \\ \hline & \bigcirc GND_S$
27	FB5RE	Inversion step-up (Channel5) error amplifier output. This pin, in combination with IN5 ⁺ RE and IN5 ⁻ RE, configures the operational amplifier (independent).	FB5RE
7 8 9 10 38 39 40 41	CSOFT1 CSOFT2 CSOFT3 CSOFT4 CSOFT5 CSOFT6 CSOFT7 CSOFT8	Soft start. Connect to GND via a capacitor to set the soft start time.	VREG (Internal constant voltage) 500Ω T T NKΩ T NKΩ S 200kΩ GND_S

Continued	from preceding	page.	
Pin No.	Pin Name	Description	Equivalent Circuit
61 62 60 59 57 56 55 53 52 51	OUT1 OUT1N OUT2 OUT2N OUT3 OUT4 OUT5 OUT6 OUT7 OUT8	Output. Connect external FET.	VOUT* VOUT*N VOUT*N GND_P*(VS*)
22	RT	Connect to GND through a resistor. This pin, together with CT, sets the oscillation frequency.	RT G GND_S
21	СТ	Connect to GND through a capacitor. This pin, together with RT, sets the oscillation frequency.	CT CT CT CT CT CT CT CT CT CT CT CT CT C
11	SCP	Connect to GND via a capacitor to set the short circuit detection circuit delay time.	SCP GND_S
12	SCP_OUT	Short circuit detection circuit output. When SCP exceeds the threshold voltage, the open collector goes OFF and this pin goes High.	SCP_OUT VREG (Internal constant voltage)

Continued	from preceding	page.	
Pin No.	Pin Name	Description	Equivalent Circuit
23	VREF	Internal constant voltage circuit output. Connect a stabilizing capacitor.	VREG (Internal constant voltage) VREF
48	CLK_IN	External clock input. Apply an external clock of the internal oscillation frequency or higher.	CLKIN VREG (Internal constant voltage) GND_S
49	CLK_OUT	Clock output. This outputs the internal or external clock frequency pulse.	CLKOUT
64 1	SYNC1 SYNC2	Channel 1 and channel 2 synchronous/diode rectification switching. Low : Synchronous rectification High : Diode rectification Switching operates independently for the corresponding channel.	SYNC* SYNC* SYNC* SYNC* SYNC* Synchronous rectification H : Diode rectification GND_S
36	SEL_CH8	Channel 8 step-up/step-down switching. High : Sets step-down Low : Sets step-up	VBIAS2 VBIAS2 SEL_CH8 SEL_CH8 GND_P2 (VS2) Channel 8 step-up/step-down switching H (VBIAS2) : step-down, L (GND) : step-up

Continued	from preceding	page.	
Pin No.	Pin Name	Description	Equivalent Circuit
46	V _{CC}	Signal system power supply	v _{cc} ()
2	VBIAS1	Power system power supply	
47	VBIAS2	(Output stage)	
24	GND_S	Signal system GND	GND_S
58	GND_P1 (VS1)	Output stage GND	
54	GND_P2 (VS2)	(Output stage GND)	
50	(NC)	Use prohibited	(NC)
63	(NC)	(Not connected pins)	

Notes

(1) Channel 8 step-up/step-down selection function

The channel 8 step-up or step-down converter selection is made by the SEL_8CH pin connection. Step-up/step-down is selected by SEL_CH8, but this selection cannot be switched during use, and is fixed to either step-up or step-down in the design stage. In addition, unlike other channels, channel 8 is not connected internally to a pull-up/pull-down resistor, so an external resistor must be connected instead.

(Mode selection using SEL_CH8)

Selected mode	SEL_CH8 connection	OUT8 resistor connection
Step-down (DOWN converter)	VBIAS2	Connect to VBIAS2 via a resistor (between the PchTr gate and VBIAS2)
Step-up (UP converter)	GND_P2 (VS2)	Connect to GND_P2 (VS2) via a resistor (between the NchTr gate and GND_P2 (VS2))

(2) Soft start time setting method

The soft start time is set with the capacitor connected between CSOFT* and GND_S. This IC has an independent soft start function for each channel, so a capacitor must be connected for each channel to set the soft start (time).

(Description of soft start operation)







(3) Setting the oscillation frequency

The internal oscillation frequency is set by the resistor connected to the RT pin and the capacitor connected to the CT pin. The waveform generated on CT is a triangular wave with the charging/discharging waveform determined by RT and CT.

$$f_{OSC} = \frac{1}{CT \times RT} [Hz]$$

The actual internal oscillation frequency deviates from the calculated value due to overshoot, undershoot and other factors, so the frequency should be confirmed in an actual set.

(4) External input CLK function (CLK_IN)

Switching operation can be synchronized with external clock input (CLK_IN) by using the CLK_IN pin.

• External clock (CLK_IN) frequency and input level

When using external clock (CLK_IN) input, input a frequency equal to the internal oscillation frequency +20% or more to CLK_IN. In addition, the CLK_IN configuration is shown in the figure "CLK_IN (input) equivalent circuit (outline)" below.

The 0.8V reference voltage and CLK_IN are compared to determine the edges, so input a signal of 0.8V or more (V_{CC} voltage or less) as the external clock (CLK_IN).

• External/internal clock switching

Set the CTL pin Low before switching between the external clock and the internal clock.

• Maximum ON duty

The maximum ON duty (Duty_MAX*) of channel 1 to channel 4 is the 85% (typ.) setting. When using the external clock (CLK_IN), the maximum ON duty (Duty_MAX*) becomes smaller, so care must be taken for the set output voltage.

(CLK_IN (input) equivalent circuit (outline))



(5) SCP function

• Description of operation

When FB1 to FB8 go High due to the load being shorted or other reason, charging to the SCP pin starts, and if output does not recover during the set time Tscp, the protective circuit (SCP) operates. When the protection circuit (SCP) operates, all channel outputs are turned OFF. When not using the protection function (SCP), the SCP pin must be shorted to GND_S with a line that is as short as possible.

When the SCP function operates and SCP_OUT goes High, all outputs are latched OFF. This latched state is canceled by setting the CTL pin Low or by turning the power supply off.

• SCP_OUT

The SCP_OUT pin functions to notify an external microcontroller or other component of the SCP (short circuit protection) and CTL status. The output configuration is an open drain output, and a pull-up resistor is used. When not used, leave this pin open.

• Switching time

The SCP_OUT switching time is set by the capacitor connected to the SCP pin.

(SCP charging operation)

(SCP and SCP_OUT operation)





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